

The SG - 207 photointerrupter high - performance standard type, combines high - output GaAs IRED with high sensitive phototransistor.

FEATURES

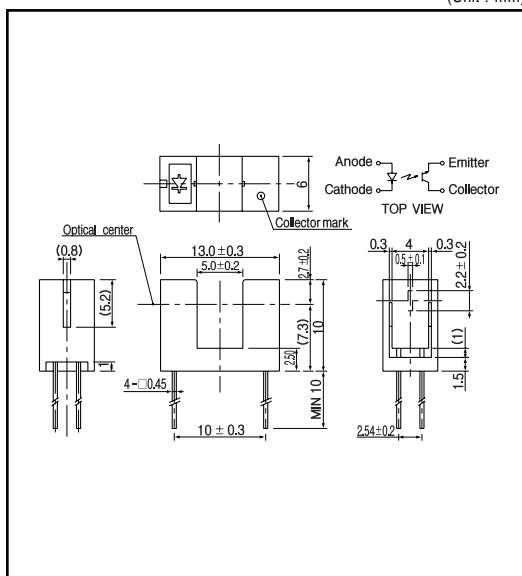
- High performance
- High - speed response
- 5mm gap.
- Widely applicable

APPLICATIONS

- Tape - end sensors
- Timing sensors
- Edge sensors
- Copiers

DIMENSIONS

(Unit : mm)



MAXIMUM RATINGS

(Ta=25 °C)

Item	Symbol	Rating	Unit
Input	P _D	100	mW
	V _R	5	V
	I _F	60	mA
	I _{FP}	1	A
Output	P _C	100	mW
	I _C	40	mA
	V _{CEO}	30	V
	V _{ECD}	5	V
	Operating temp.	Topr.	-20~+85
	Storage temp.	Tstg.	-30~+85
Soldering temp. ²	Tsol.	240	

*1. t w 100 μsec. period : T=10msec.

*2. For MAX. 5 seconds at the position of 2mm from the package

ELECTRO-OPTICAL CHARACTERISTICS

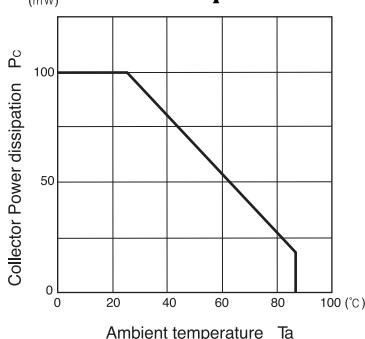
(Ta=25 °C)

Item	Symbol	Conditions	Min.	Typ.	Max.	Unit.
Input	V _F	I _F =30mA		1.2	1.5	V
	I _R	V _R =5V			10	μA
	C _t	V=0, f=1KHz		25		pF
	λ _p			940		nm
Output	I _{CEO}	V _{CEO} =10V			0.1	μA
Light current	I _L	V _{CE} =5V, I _F =20mA	0.25			mA
C-E saturation voltage	V _{CE(sat)}	I _F =30mA, I _L =0.1mA			0.3	V
Switching speeds	Rise time	tr	V _{CC} =5V, I _L =2mA	5		μsec.
	Fall time	tf	R _L =100	5		μsec.

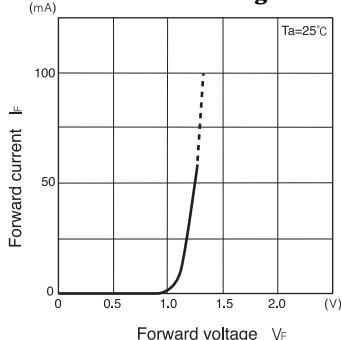
Photo interrupters(Transmissive)

SG - 207

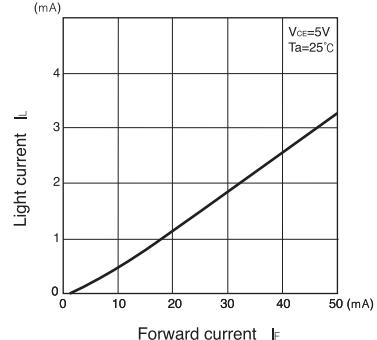
**Collector power dissipation Vs.
Ambient temperature**



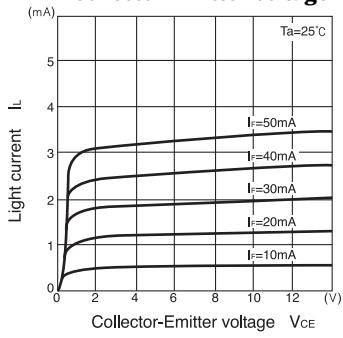
**Forward current Vs.
Forward voltage**



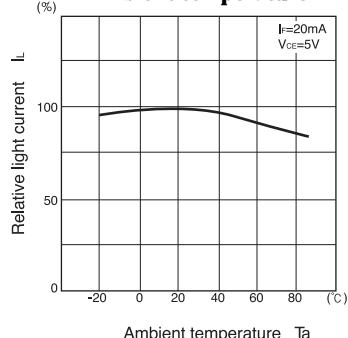
**Light current Vs.
Forward current**



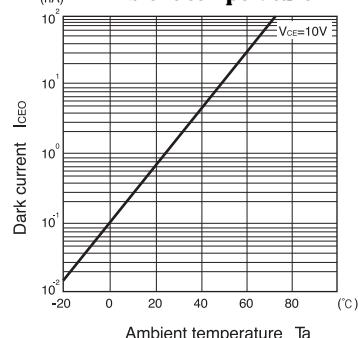
**Light current Vs.
Collector-Emitter voltage**



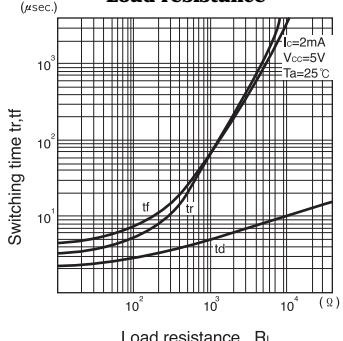
**Relative light current Vs.
Ambient temperature**



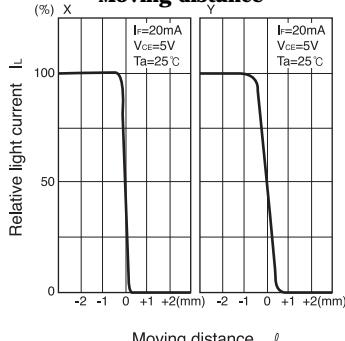
**Dark current Vs.
Ambient temperature**



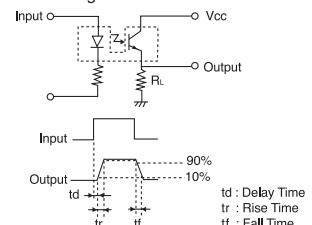
**Switching time Vs.
Load resistance**



**Relative light current Vs.
Moving distance**



Switching time measurement circuit



Method of measuring position characteristic

